

ZXT13P20DE6

20V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

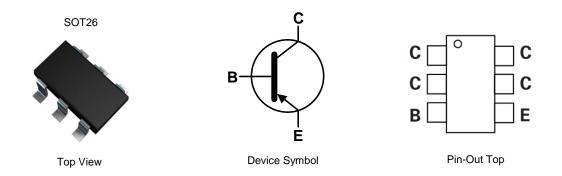
- BV_{CEO} > -20V
- I_C = -3.5A Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- R_{CE(sat)} = 75mΩ for a Low Equivalent On-Resistance
- Low Saturation Voltage of <-130mV max @ -1A
- h_{FE} Characterized up to -10A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 ⁽²⁾
- Weight: 0.015 grams (Approximate)

Applications

- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control



Ordering Information (Notes 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13P20DE6TA	P20D	7	8	3,000

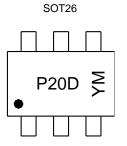
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



P20D = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	201	5	2016	2017	2018	2019	2020	202	1 20	22	2023	2024	2025
Code	C	•	D	E	F	G	Н			J	K	 L	M
Mont	h	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	;	1	2	3	4	5	6	7	8	9	0	N	D

1 of 7 www.diodes.com



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7.5	V
Base Current	IB	-500	mA
Continuous Collector Current	lc	-3.5	A
Peak Pulse Collector Current	I _{CM}	-10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)		1.1 8.8	W mW/°C	
Linear Derating Factor	(Note 6)	PD	1.7 13.6		
Thermal Resistance, Junction to Ambient	(Note 5) (Note 6)	- R _{0JA}	113 73	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	R _{θJL}	18.61		
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C		

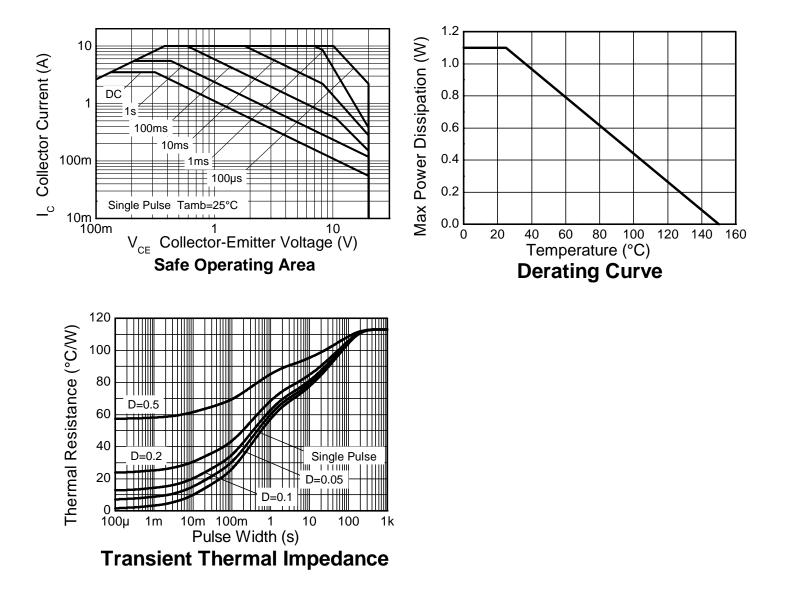
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air 6. Some as Note 5, except the device is measured at t ≤ 5 seconds.
7. Thermal resistance from junction to solder-point (at the end of the collector leads).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Characteristic Symbol Min Max Unit Test Condition Тур OFF CHARACTERISTICS Collector-Base Breakdown Voltage **BV**CBO -25 V -55 $I_C = -100 \mu A$ ____ Collector-Emitter Breakdown Voltage (Note 9) -20 -50 V $I_C = -10 \text{mA}$ $\mathsf{BV}_{\mathsf{CEO}}$ ____ -7.5 Emitter-Base Breakdown Voltage -8.5 V **BV**_{EBO} $I_{E} = -100 \mu A$ Collector-Base Cut-Off Current -100 nA $V_{CB} = -20V$ Ісво ____ Emitter Cut-Off Current -100 nA $V_{EB} = -6V$ I_{EBO} ____ ____ Collector-Emitter Cut-Off Current -100 _ nA $V_{CES} = -20V$ ____ ICES **ON CHARACTERISTICS** (Note 9) 300 500 I_C = -10mA, V_{CE} = -2V ____ 300 450 900 $I_{C} = -1A, V_{CE} = -2V$ ____ DC Current Gain h_{FE} 150 250 $I_{C} = -3.5A, V_{CE} = -2V$ _ ____ 10 I_C = -10A, V_{CE} = -2V -10 -15 $I_{C} = -100 \text{mA}, I_{B} = -10 \text{mA}$ ____ -100 -130 Collector-Emitter Saturation Voltage m٧ $I_{C} = -1A, I_{B} = -10mA$ V_{CE(sat)} ____ -165 -250 $I_C = -3.5A$, $I_B = -350mA$ ____ Base-Emitter Saturation Voltage V_{BE(sat)} ____ -1.1 V $I_C = -3.5A, I_B = -350mA$ ____ Base-Emitter Turn-On Voltage V_{BE(on)} -0.9 V $I_C = -3.5A, V_{CE} = -2V$ SMALL SIGNAL CHARACTERISTICS Current Gain-Bandwidth Product 90 MHz $V_{CE} = -10V, I_{C} = -50mA, f = 50MHz$ f_T ____ Output Capacitance 62 pF V_{CB} = -10V, f = 1MHz Cobo ____ ____ Turn-On Time 95 ns $V_{CC} = -10V, I_C = -2A$ t_(on) Turn-Off Time 395 $I_{B1} = I_{B2} = -40 \text{mA}$ ns t_(off)

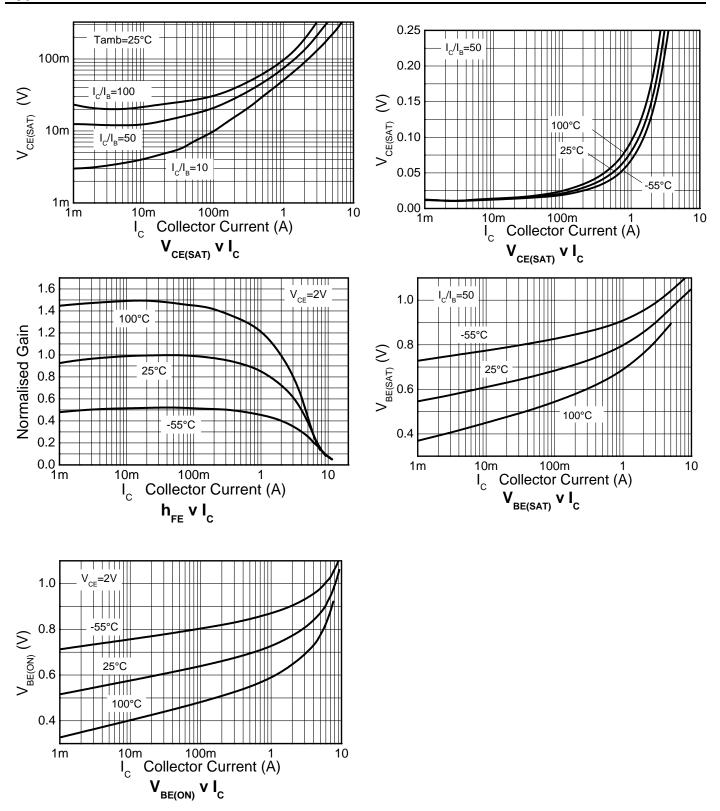
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

9. Measured under pulsed conditions; pulse width \leq 300µs, duty cycle \leq 2%. Note:



ZXT13P20DE6

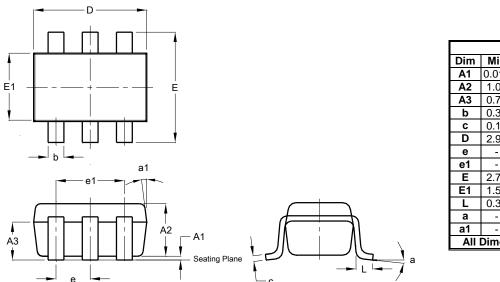
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline

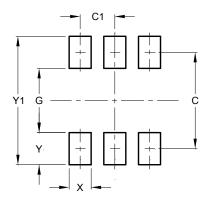
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26 Max Dim Min Тур 0.013 0.10 0.05 1.10 1.00 1.30 0.75 0.70 0.80 0.35 0.50 0.38 0.10 0.20 0.15 2.90 3.10 3.00 0.95 -1.90 2.70 3.00 2.80 1.50 1.70 1.60 0.35 0.55 0.40 8° -7° --All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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